



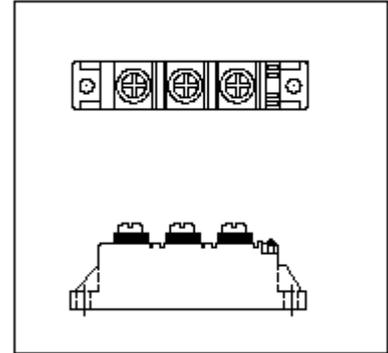
## POWER MODULES

### IRK.26, .41, .56, .71, .91 SERIES

### High Voltage Thyristor/Diode and Thyristor/Thyristor

#### FEATURES

- ⊕ *Electrically isolated base plate.*
- ⊕ *3500 V<sub>RMS</sub> isolating voltage.*
- ⊕ *Simplified mechanical designs, rapid assembly.*
- ⊕ *Auxiliary cathode terminals for wiring convenience.*
- ⊕ *High surge capability.*
- ⊕ *Wide choice of circuit configurations.*
- ⊕ *Large creepage distances.*



#### DESCRIPTION

These IRK series of Power Modules use power diodes and thyristors in a variety of circuit configurations. The semiconductor chips are electrically isolated from the metal base, allowing common heatsinks and compact assemblies to be built. They can be interconnected to form single phase or three phase bridges or AC controllers. These modules are intended for general purpose applications such as regulated power supplies, lighting circuits and temperature and motor speed control circuits.

#### MAJOR RATINGS & CHARACTERISTICS

Parameters	IRK.26	IRK.41	IRK.56	IRK.71	IRK.91	Units
$I_{T(AV)}$ or $I_{F(AV)}$ @ 85°C	27	45	60	75	95	A
$I_{O(RMS)}$ (*)	60	100	135	165	210	A
$I_{TSM}$ @ 50 Hz	400	850	1310	1665	1785	A
$I^2t$ @ 50 Hz	800	3610	8500	13860	15910	A <sup>2</sup> s
$I^2\sqrt{t}$	8000	36100	85000	138600	159100	A <sup>2</sup> √s
$V_{RRM}$ range	400V - 1600V					V
$T_{STG}$	-40 to 125					°C
$T_J$	-40 to 125					°C

(\*) As A.c. Switch

# POWER MODULES

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### ELECTRICAL SPECIFICATION

#### VOLTAGE RATINGS

Type Number	Voltage Code	$V_{RRM} / V_{DRM}$ , max. repetitive peak reverse and off-state blocking voltage V	$V_{RSM}$ , max. non-repetitive peak reverse voltage V	$I_{DRM} / I_{RRM}$ max. @ 125°C mA
	04	400	500	20
IRK.26/41/56/71/91	06	600	700	20
	08	800	900	20
	10	1000	1100	20
	12	1200	1300	20
	14	1400	1500	20
	16	1600	1700	20

#### ON-STATE CONDUCTION

Parameter	IRK.26	IRK.41	IRK.56	IRK.71	IRK.91	Units	Conditions
$I_{T(AV)}$ $I_{F(AV)}$	27	45	60	75	95	A	180°C conduction, half sine wave $T_C = 85^\circ\text{C}$
$I_{O(RMS)}$	60	100	135	165	210	A	As AC switch
$I_{TSM}$ or $I_{FSM}$	400	850	1310	1665	1785	A	t = 10ms No voltage reapplied Sinusoidal half wave, Initial $T_J = T_J$ max.
	335	715	1100	1400	1500	A	t = 10ms 100% $V_{RRM}$ reapplied
	470	940	1450	1850	2000	A	t = 10ms $T_J = 25^\circ\text{C}$ No voltage reapplied
$I^2t$	800	3610	8500	13860	15910	A <sup>2</sup> s	t = 10ms No voltage reapplied Initial $T_J = T_J$ max.
	560	2560	6050	9800	11250	A <sup>2</sup> s	t = 10ms 100% $V_{RRM}$ reapplied
	1100	4420	10050	17110	20000	A <sup>2</sup> s	t = 10 ms $T_J = 25^\circ\text{C}$ No voltage reapplied
$I^2\sqrt{t}$	8000	36100	85000	138600	159100	A <sup>2</sup> s	t = 0.1 to 10ms. No voltage reapplied.
$V_{T(TO)}$	0.92	0.88	0.85	0.82	0.80	V	Low level (3)
	0.95	0.91	0.88	0.85	0.85	V	High level (4)
$r_t$	12.11	5.90	3.53	3.00	2.40	mΩ	Low level (3)
	11.82	5.74	3.41	2.90	2.25	mΩ	High level (4)
$V_{TM}$	1.95	1.81	1.54	1.59	1.58	V	$I_{TM} = \pi \times I_{T(AV)}$ $T_J = 25^\circ\text{C}$
$V_{FM}$	1.95	1.81	1.54	1.59	1.58	V	$I_{FM} = \pi \times I_{F(AV)}$ 180°conduction
di/dt	150	150	150	150	150	A/μs	$T_J = 25^\circ\text{C}$ , from 0.67 $V_{DRM}$ $I_{TM} = \pi \times I_{T(AV)}$ , $I_g = 500\text{mA}$ $t_r < 0.5 \mu\text{s}$ , $t_p > 6\mu\text{s}$
$I_H$	200	200	200	200	200	mA	$T_J = 25^\circ\text{C}$ , anode supply = 6V, resistive load, gate open circuit
$I_L$	400	400	400	400	400	mA	$T_J = 25^\circ\text{C}$ , anode supply = 6V, resistive load

(1)  $I^2t$  for time  $t_x = I^2\sqrt{t} \times \sqrt{t_x}$

(2) Average power =  $V_{T(TO)} \times I_{T(AV)} + r_t \times (I_{T(RMS)})^2$

(3)  $16.7\% \times \pi \times I_{AV} < I < \pi \times I_{AV}$

(4)  $\pi \times I_{AV} < I < 20 \times \pi \times I_{AV}$

# POWER MODULES

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### ELECTRICAL SPECIFICATION TRIGGERING

	Parameter	IRK.26	IRK.41	IRK.56	IRK.71	IRK.91	Units	Conditions	
$P_{GM}$	Max. peak gate power	10	10	10	12	12	W		
$P_{G(AV)}$	Max. average gate power	2.5	2.5	2.5	3.0	3.0	W		
$I_{GM}$	Max. peak gate current	2.5	2.5	2.5	3.0	3.0	A		
$-V_{GM}$	Max. peak negative gate voltage	10	10	10	10	10	V		
$V_{GT}$	Max. gate voltage required to trigger	4.0	4.0	4.0	4.0	4.0	V	$T_J = -40^\circ\text{C}$	Anode supply = 6V resistive load
		2.5	2.5	2.5	2.5	2.5	V	$T_J = 25^\circ\text{C}$	
		1.7	1.7	1.7	1.7	1.7	V	$T_J = 125^\circ\text{C}$	
$I_{GT}$	Max. gate current required to trigger	170	270	270	270	270	mA	$T_J = -40^\circ\text{C}$	Anode supply = 6V resistive load
		150	150	150	150	150	mA	$T_J = 25^\circ\text{C}$	
		80	80	80	80	80	mA	$T_J = 125^\circ\text{C}$	
$V_{GD}$	Max. gate voltage that will not trigger	0.25	0.25	0.25	0.25	0.25	V	$T_J = 125^\circ\text{C}$ rated $V_{DRM}$ applied	
$I_{GD}$	Max. gate current that will not trigger	6.0	6.0	6.0	6.0	6.0	mA	$T_J = 125^\circ\text{C}$ rated $V_{DRM}$ applied	

### BLOCKING

$I_{RRM}$ $I_{DRM}$	Max. peak reverse and off-state leakage current at $V_{RRM}$ , $V_{DRM}$	15	15	15	15	15	mA	$T_J = 125^\circ\text{C}$ , gate open circuit
$V_{INS}$	RMS isolation voltage	3500	3500	3500	3500	3500	V	50 Hz circuit to base, all terminal shorted, $t = 1\text{s}$
dv/dt	Max. critical rate of rise of off-state Voltage	500	500	500	500	500	V/ $\mu\text{s}$	$T_J = 125^\circ\text{C}$ linear to $0.67V_{DRM}$ , gate open circuit

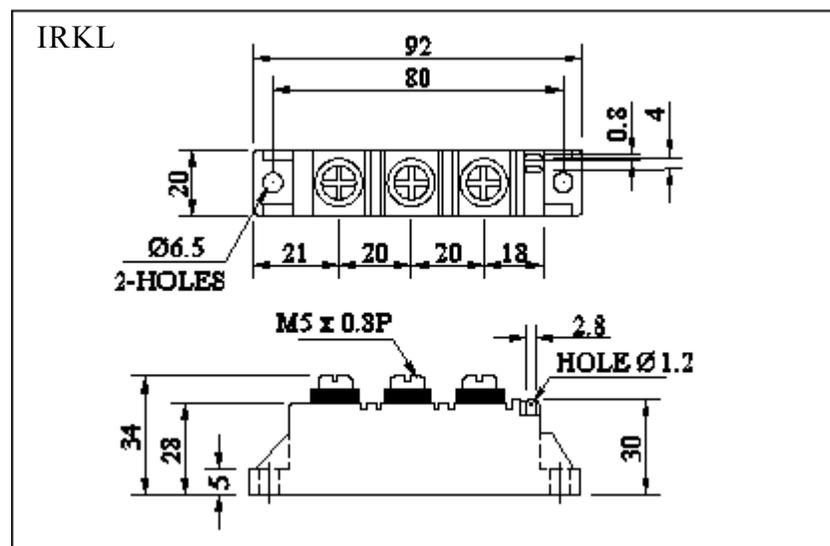
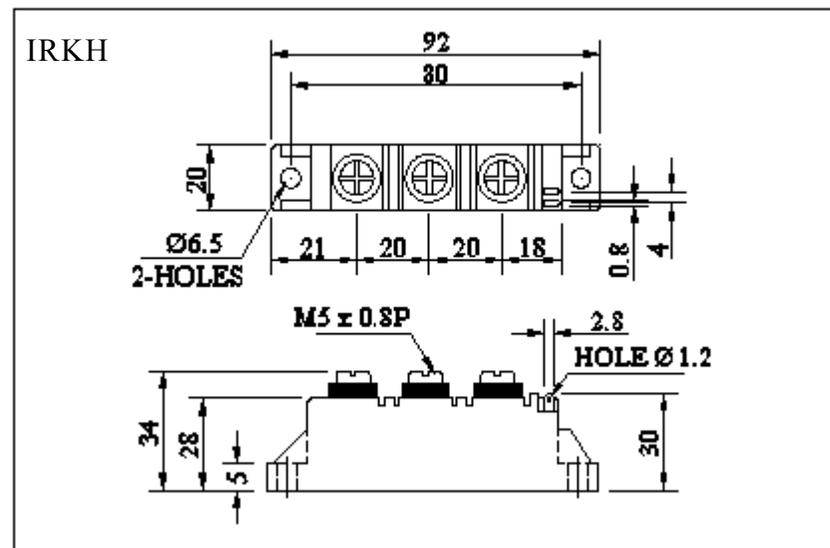
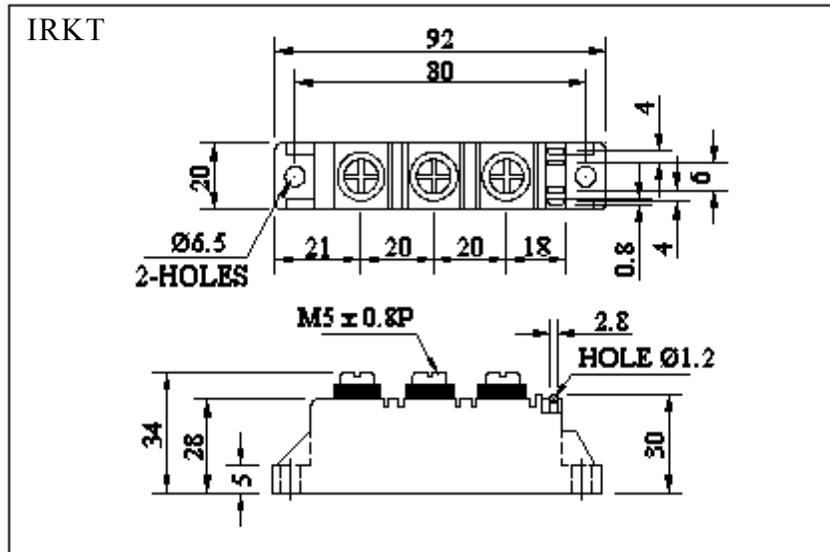
### THERMAL AND MECHANICAL SPECIFICATIONS

	Parameter	IRK.26	IRK.41	IRK.56	IRK.71	IRK.91	Units	Conditions	
$T_J$	Junction operating temperature range	-40 to 125						$^\circ\text{C}$	
$T_{stg}$	Storage temp. range	-40 to 125						$^\circ\text{C}$	
$R_{thJC}$	Max. internal thermal resistance, junction to case	0.31	0.23	0.20	0.165	0.135	K/W	Per module, D.C. operation	
$R_{thCS}$	Max. thermal resistance case to heatsink	0.1						K/W	Mounting surface flat, smooth and greased (per module)
T	Mounting torque $\pm 10\%$ Module to heatsink	5						Nm	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound.
	Busbar to module	3						Nm	
Wt	Approximate weight	75						g	
	Case style	To-240AA							

# POWER MODULES

## IRK.26, .41, .56, .71, .91 SERIES

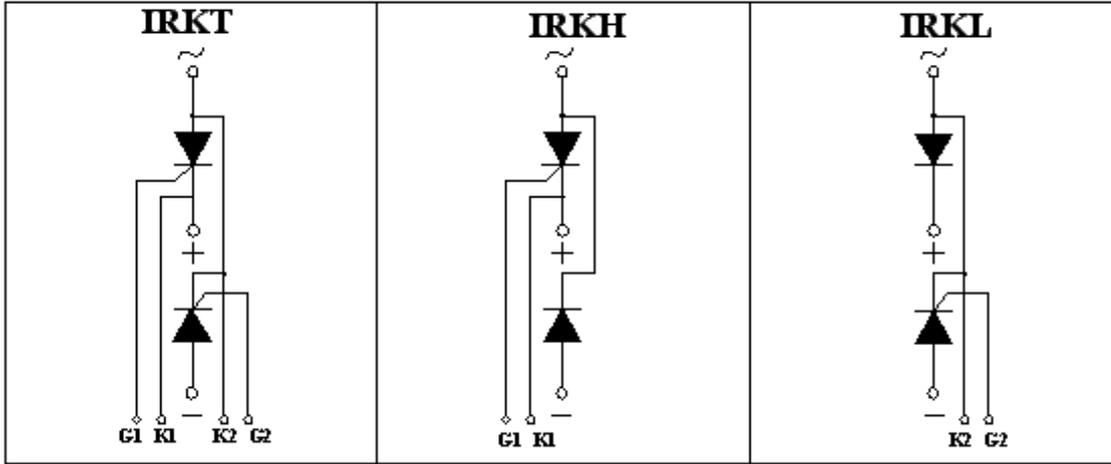
### OUTLINE DIAGRAM



# POWER MODULES

IRK.26 Series

## Circuit Configuration Table



## Ordering Information Table

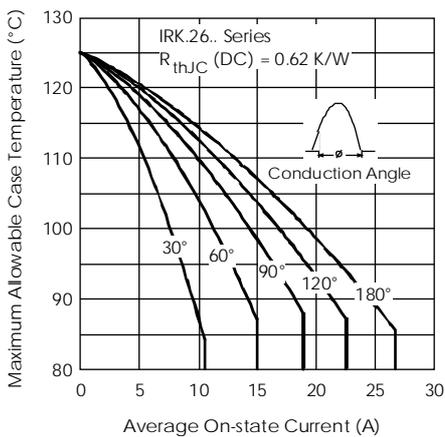
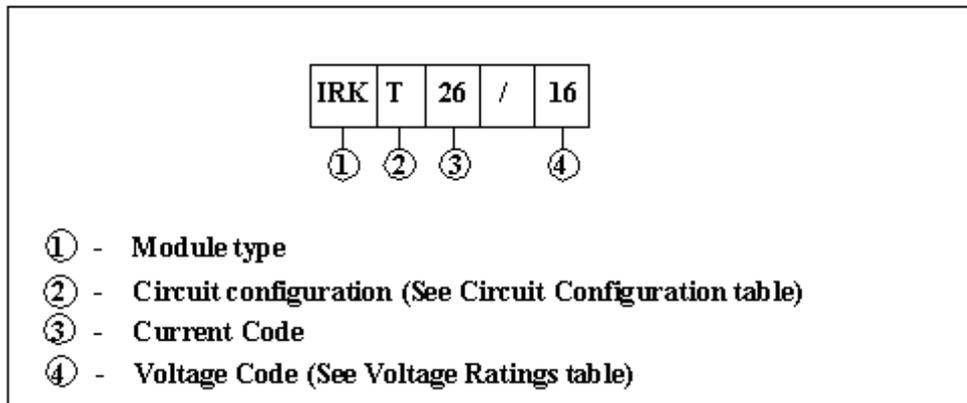


Fig. 1 - Current Ratings Characteristics

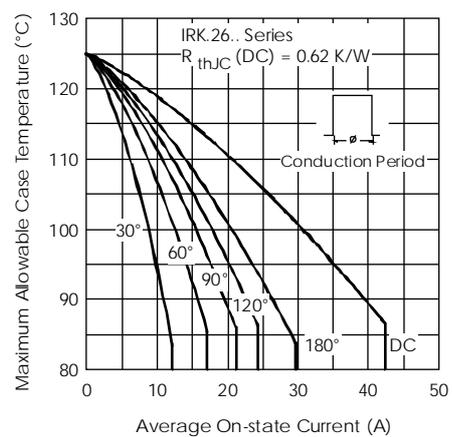


Fig. 2 - Current Ratings Characteristics

# POWER MODULES

## IRK.26 Series

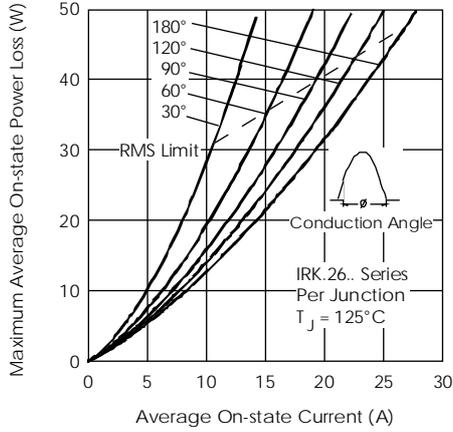


Fig. 3 - On-state Power Loss Characteristics

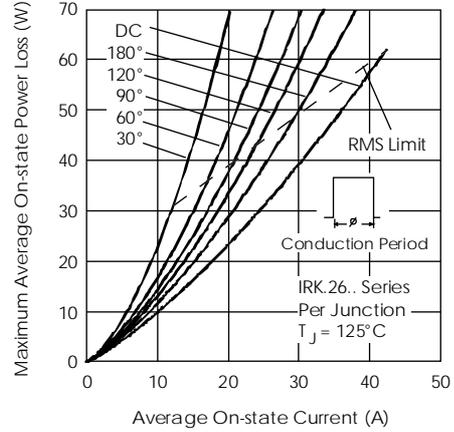


Fig. 4 - On-state Power Loss Characteristics

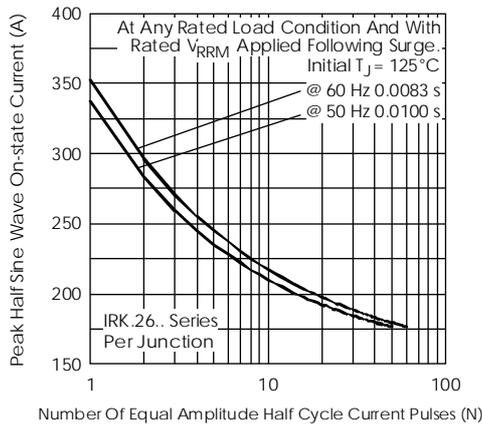


Fig. 5 - Maximum Non-Repetitive Surge Current

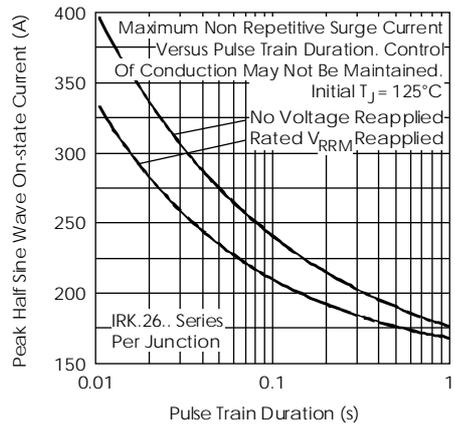


Fig. 6 - Maximum Non-Repetitive Surge Current

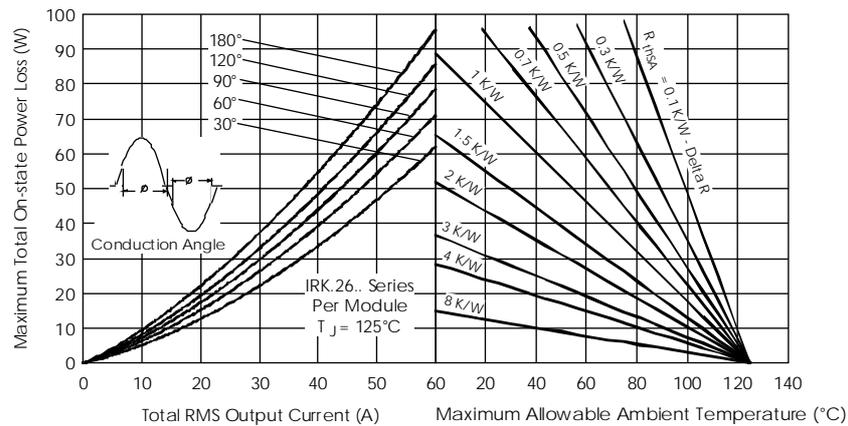


Fig. 7 - On-state Power Loss Characteristics

# POWER MODULES

IRK.26 Series

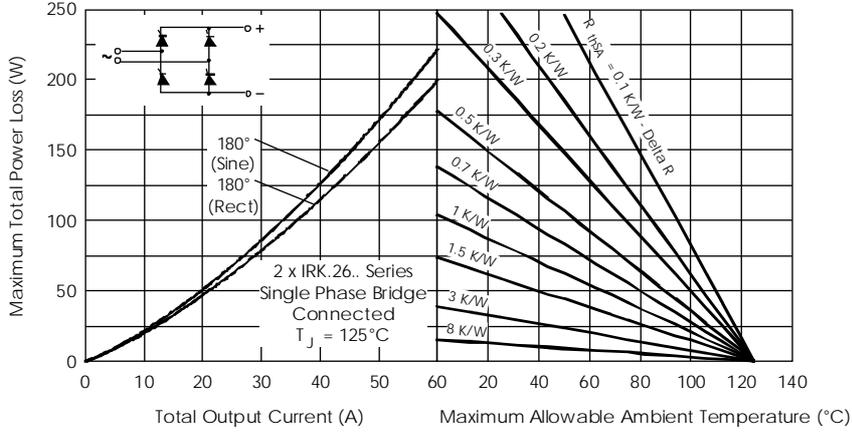


Fig. 8 - On-state Power Loss Characteristics

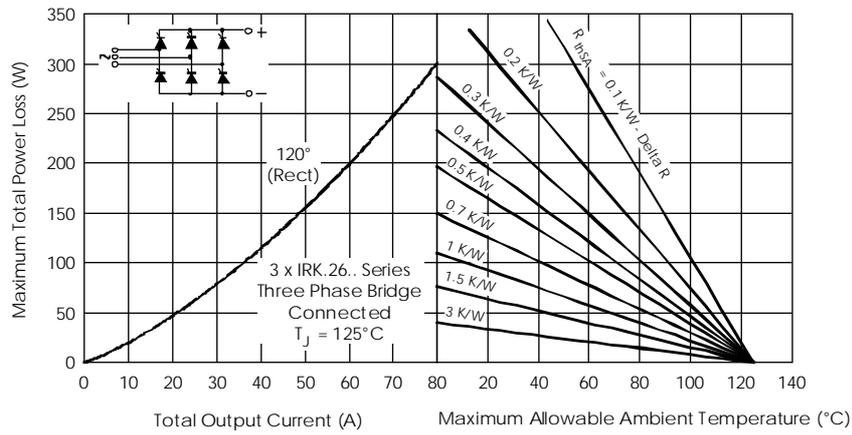


Fig. 9 - On-state Power Loss Characteristics

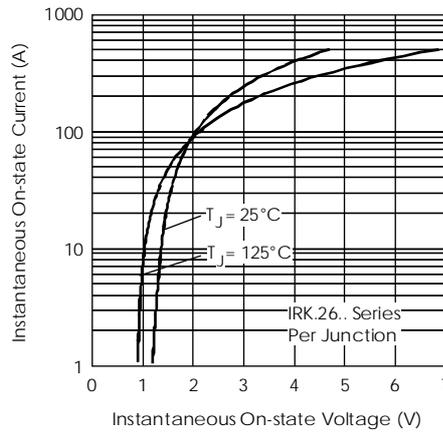


Fig. 10 - On-state Voltage Drop Characteristics

# POWER MODULES

## IRK.26 Series

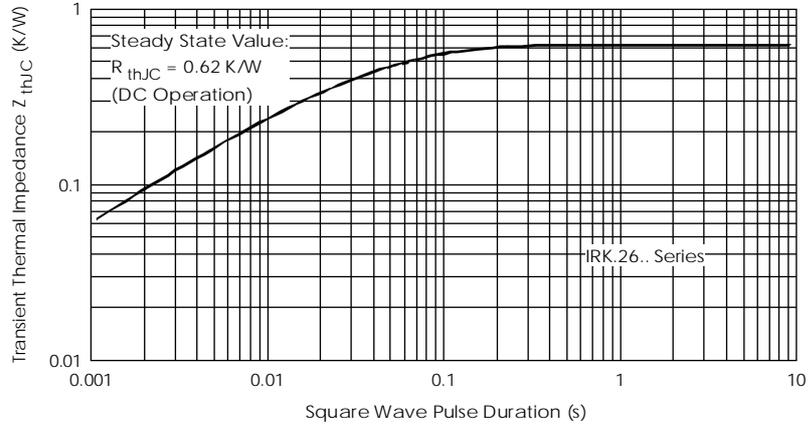


Fig. 11 - Thermal Impedance  $Z_{thJC}$  Characteristics

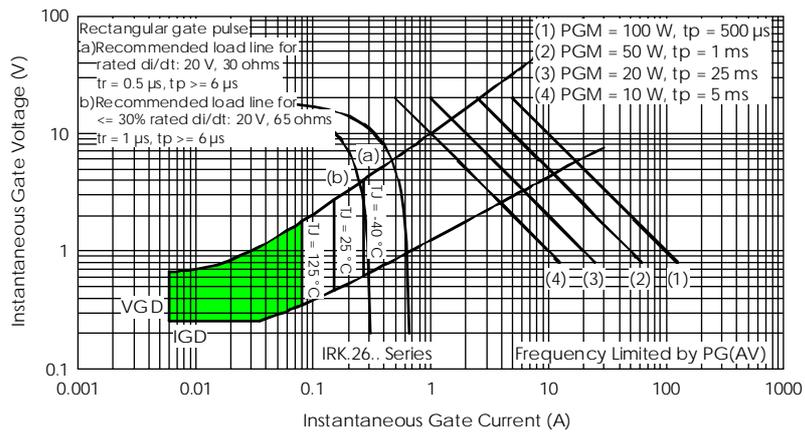
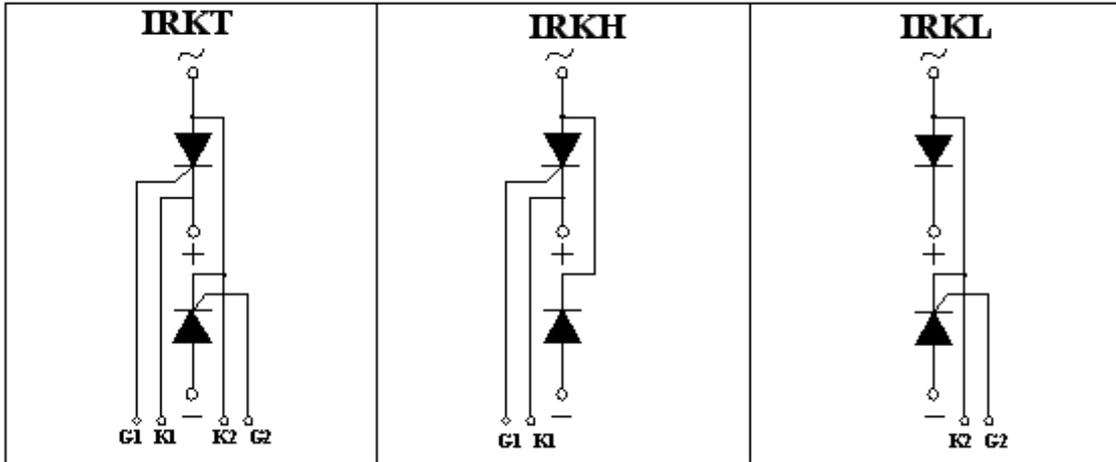


Fig. 12- Gate Characteristics

# POWER MODULES

IRK.41, .56 Series

## Circuit Configuration Table



## Ordering Information Table

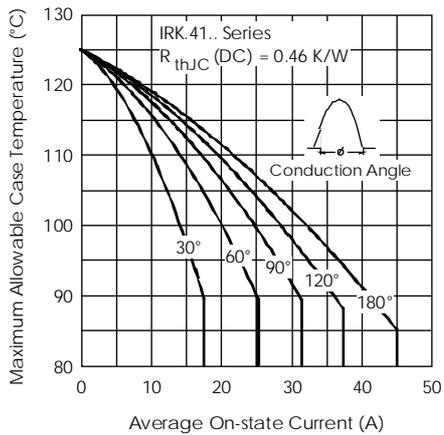
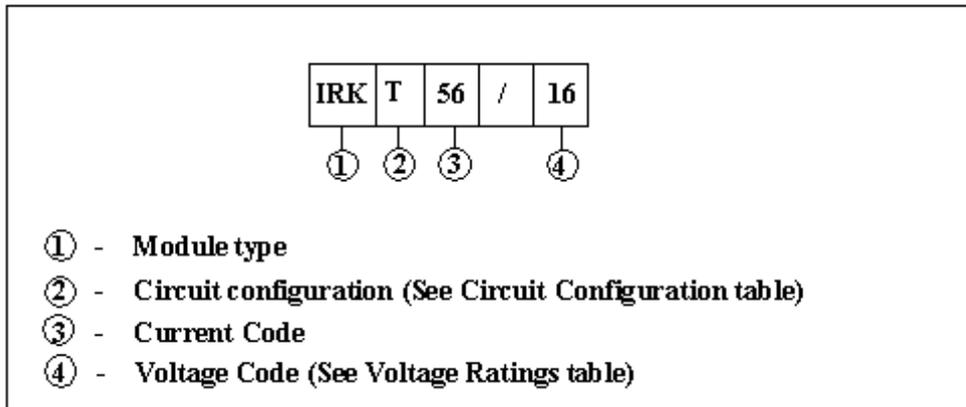


Fig. 13 - Current Ratings Characteristics

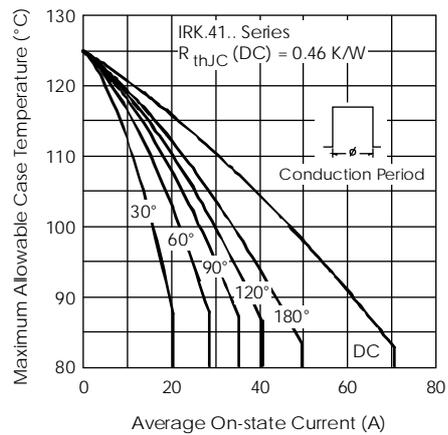


Fig. 14 - Current Ratings Characteristics

# POWER MODULES

## IRK.41, .56 Series

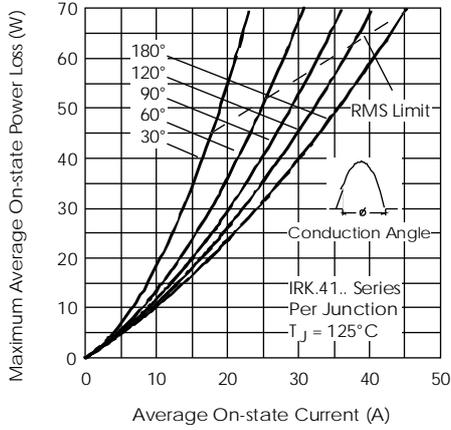


Fig. 15- On-state Power Loss Characteristics

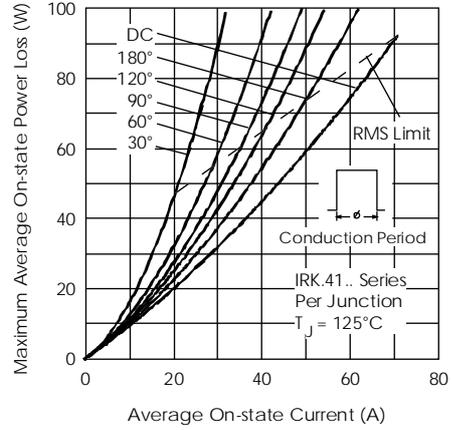


Fig. 16- On-state Power Loss Characteristics

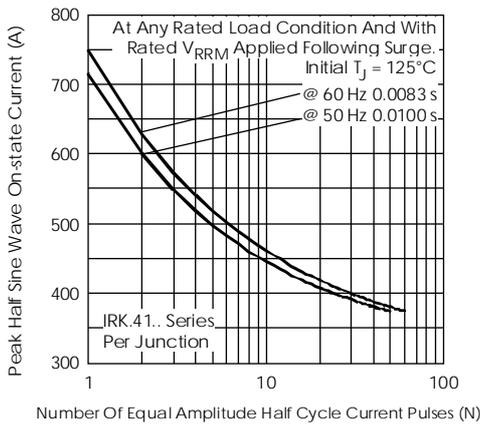


Fig. 17 - Maximum Non-Repetitive Surge Current

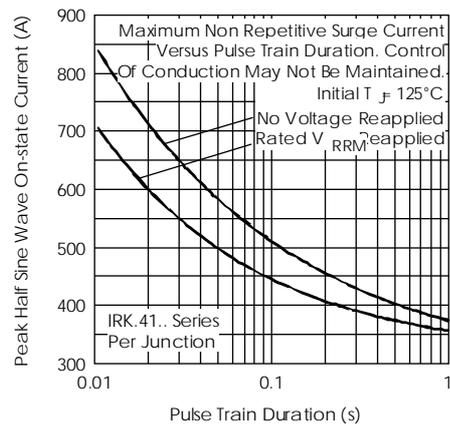


Fig. 18 - Maximum Non-Repetitive Surge Current

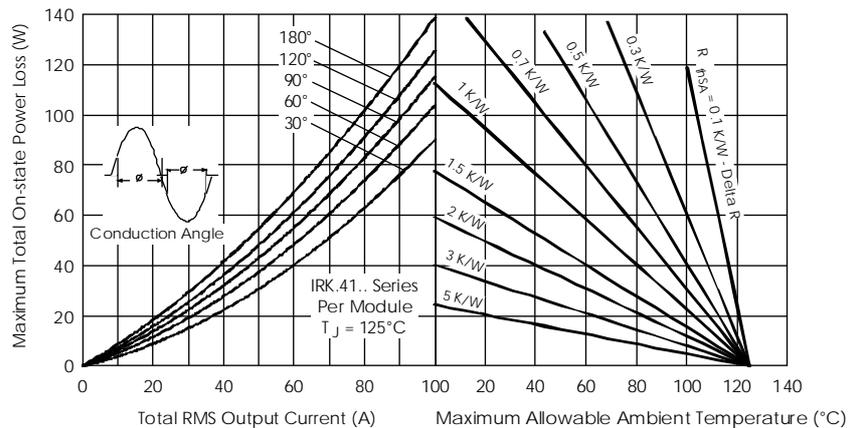


Fig. 19 - On-state Power Loss Characteristics

# POWER MODULES

IRK.41, .56 Series

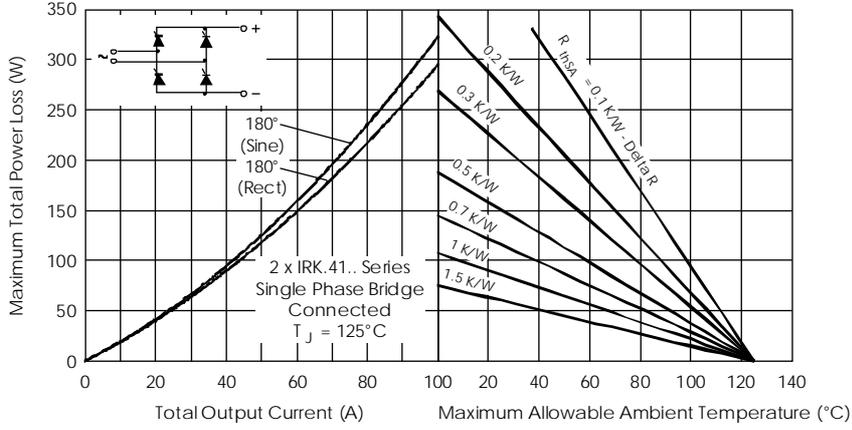


Fig. 20 - On-state Power Loss Characteristics

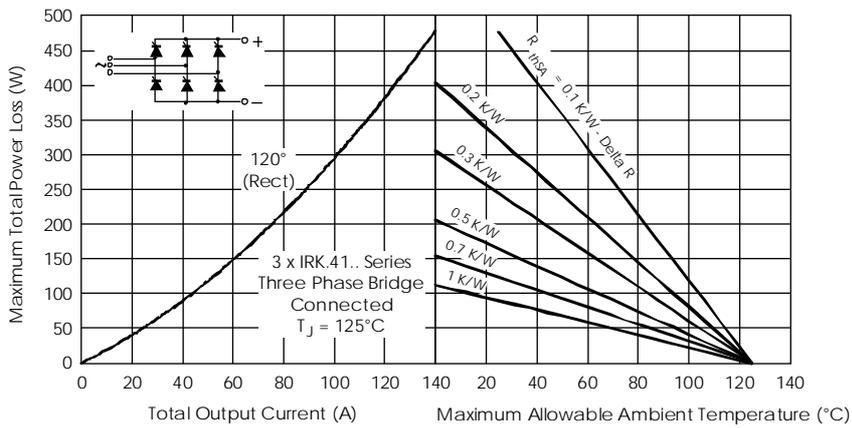


Fig. 21 - On-state Power Loss Characteristics

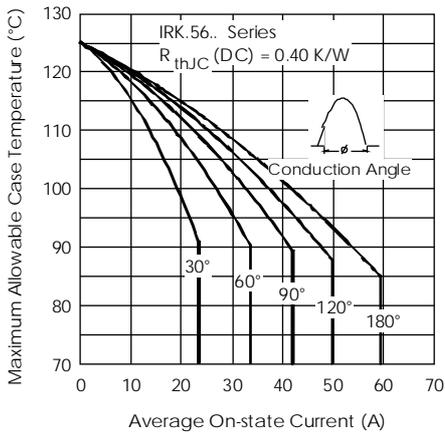


Fig. 22 - Current Ratings Characteristics

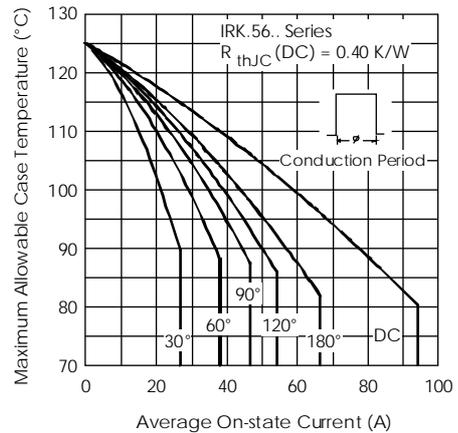


Fig. 23 - Current Ratings Characteristics



# POWER MODULES

IRK.41, .56 Series

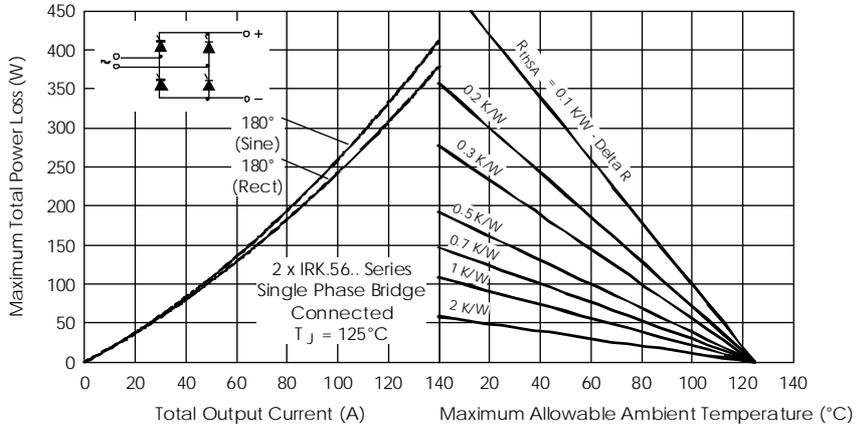


Fig. 29 - On-state Power Loss Characteristics

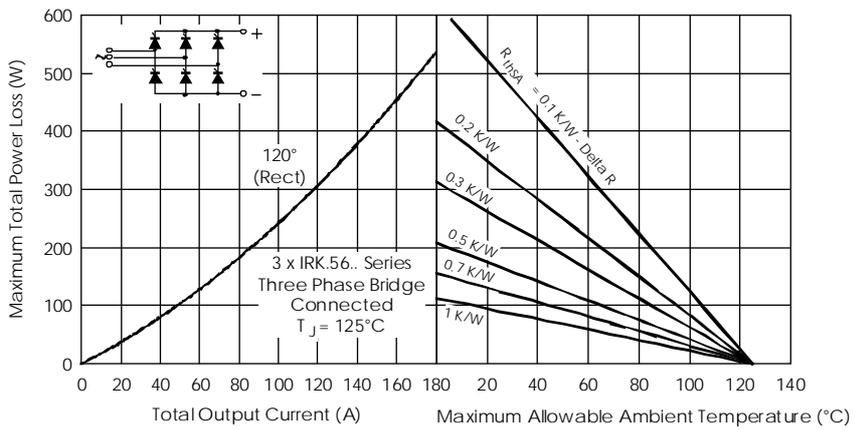


Fig. 30 - On-state Power Loss Characteristics

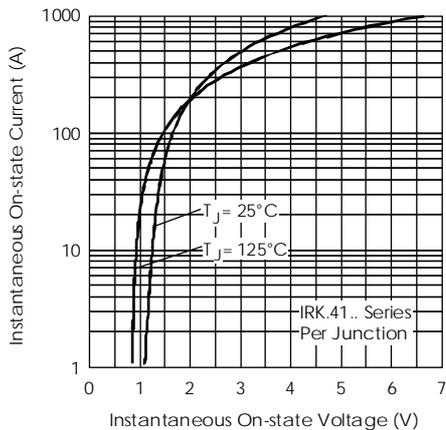


Fig. 31 - On-state Voltage Drop Characteristics

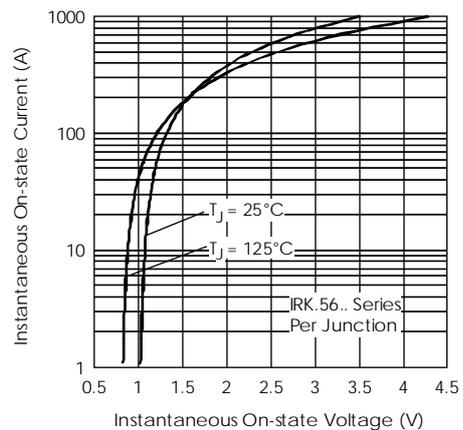


Fig. 32 - On-state Voltage Drop Characteristics

# POWER MODULES

## IRK.41, .56 Series

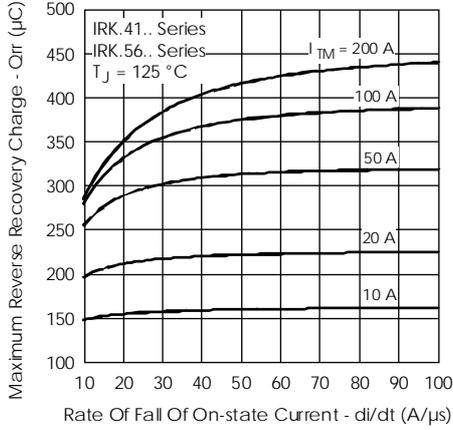


Fig. 33 - Recovery Charge Characteristics

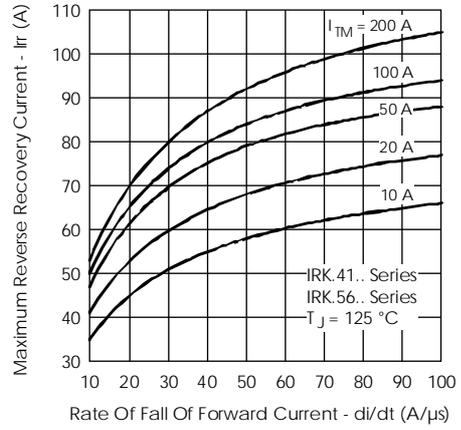


Fig. 34 - Recovery Current Characteristics

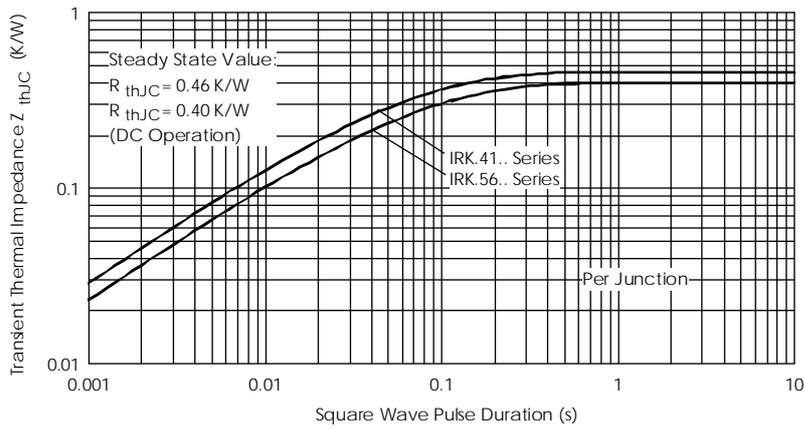


Fig. 35 - Thermal Impedance  $Z_{thJC}$  Characteristics

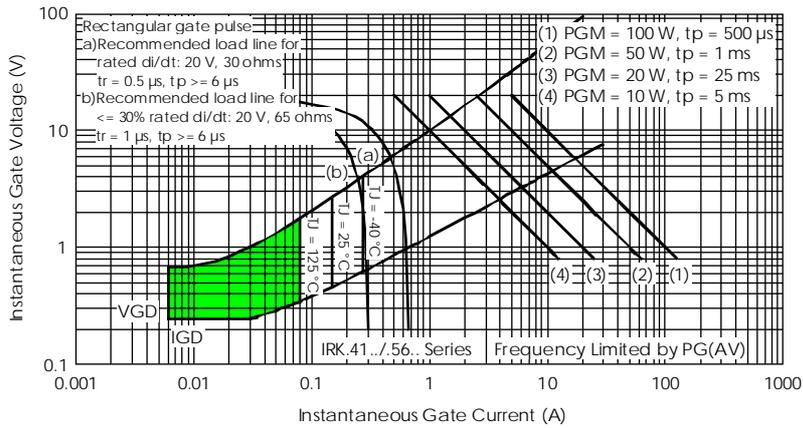
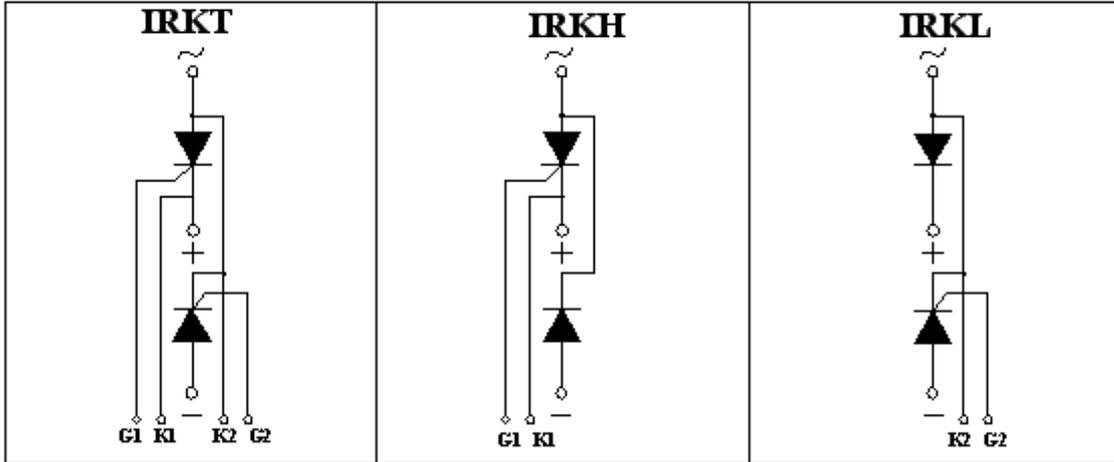


Fig. 36 - Gate Characteristics

# POWER MODULES

IRK.71, .91 Series

## Circuit Configuration Table



## Ordering Information Table

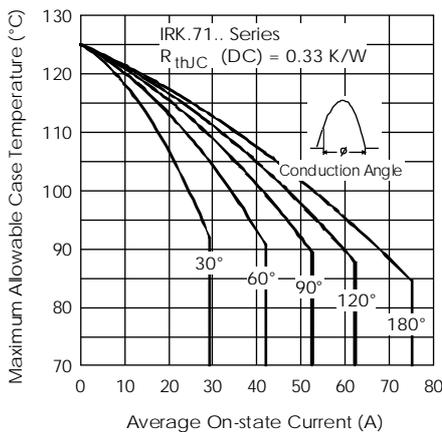
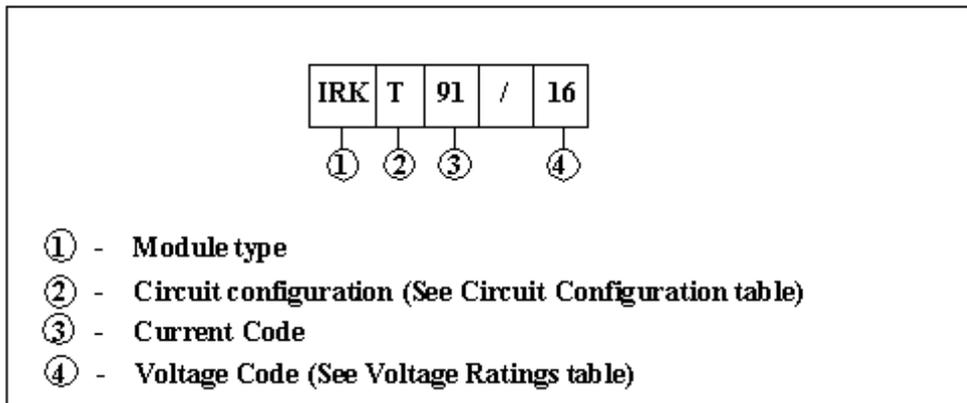


Fig. 37- Current Ratings Characteristics

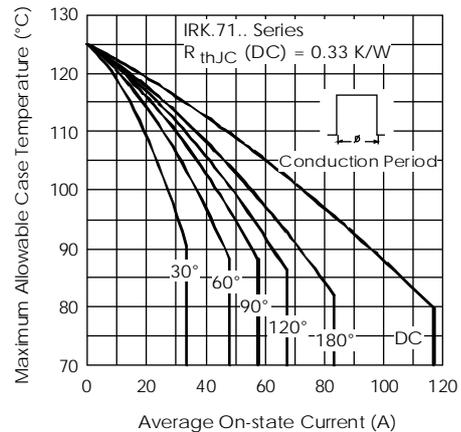


Fig. 38 - Current Ratings Characteristics

# POWER MODULES

## IRK.71, .91 Series

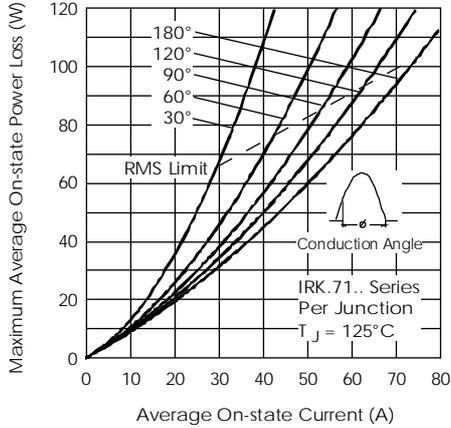


Fig. 39- On-state Power Loss Characteristics

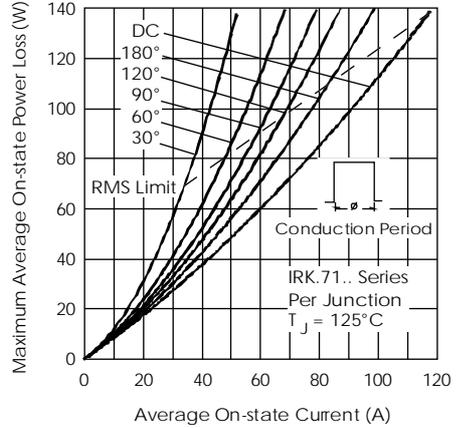


Fig.40 - On-state Power Loss Characteristics

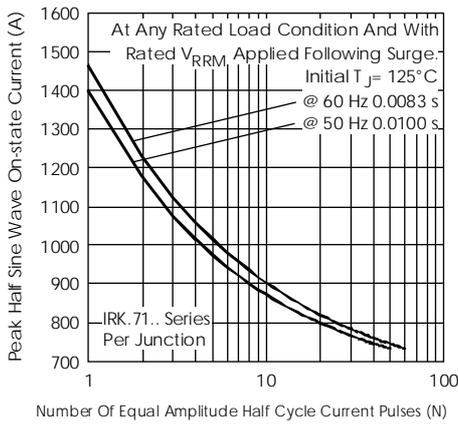


Fig. 41 - Maximum Non-Repetitive Surge Current

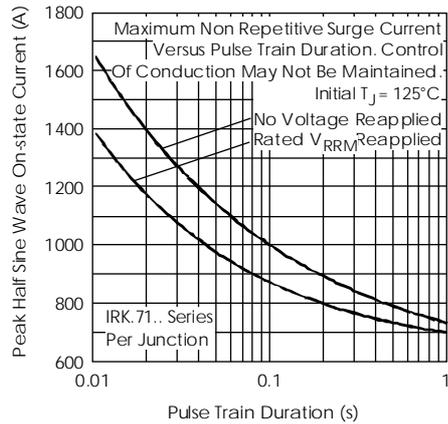


Fig. 42 - Maximum Non-Repetitive Surge Current

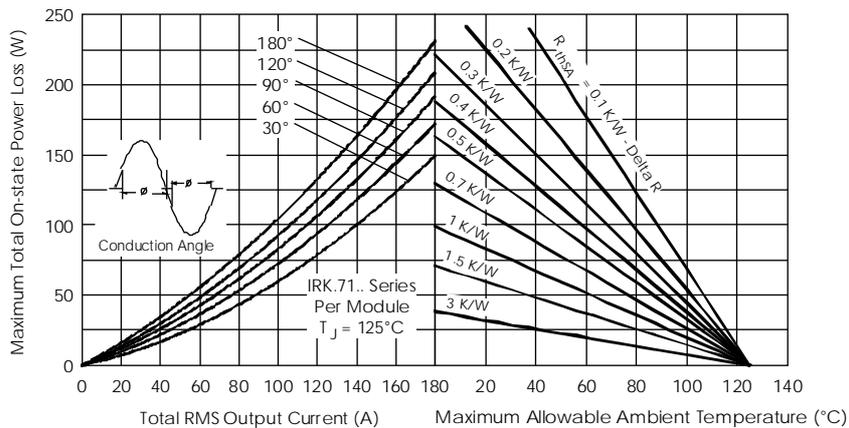


Fig. 43 - On-state Power Loss Characteristics

# POWER MODULES

IRK.71, .91 Series

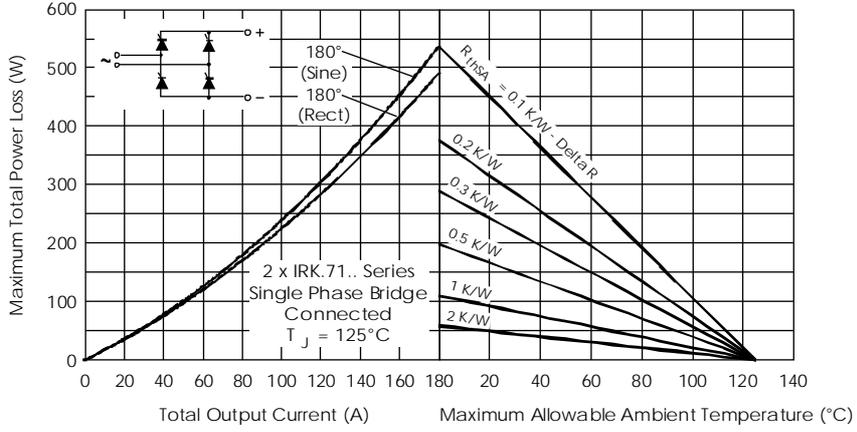


Fig. 44 - On-state Power Loss Characteristics

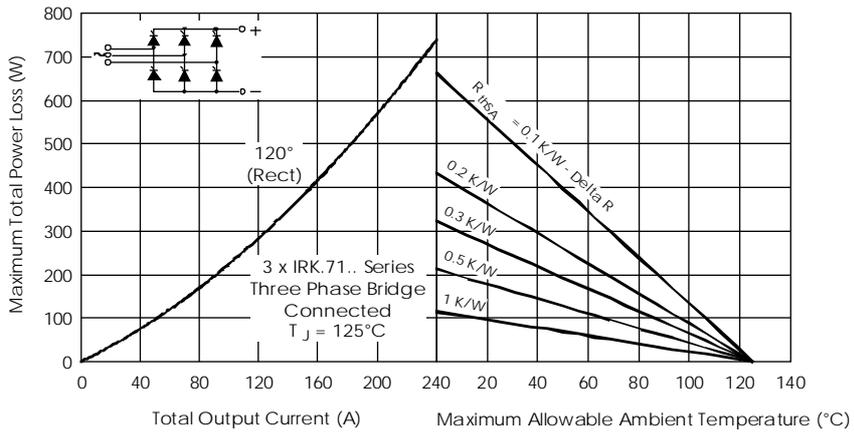


Fig. 45 - On-state Power Loss Characteristics

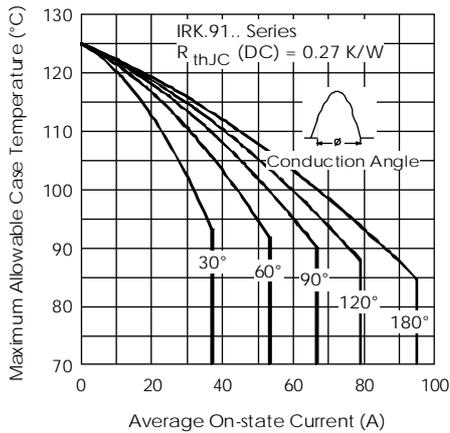


Fig. 46 - Current Ratings Characteristics

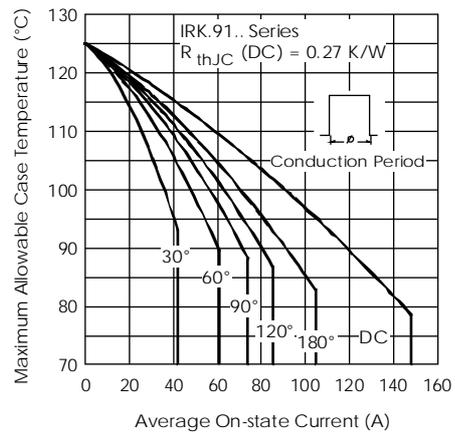


Fig. 47 - Current Ratings Characteristics

# POWER MODULES

## IRK.71, .91 Series

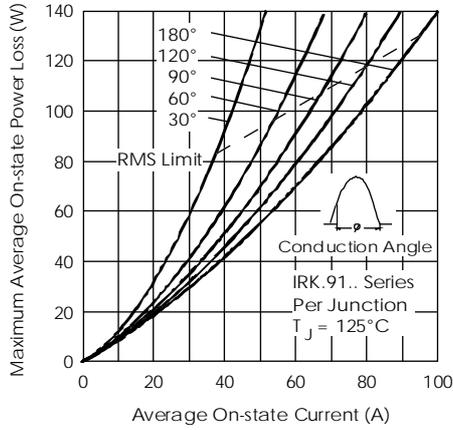


Fig. 48 - On-state Power Loss Characteristics

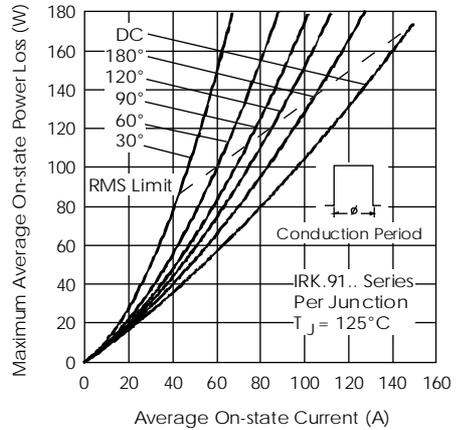


Fig. 49 - On-state Power Loss Characteristics

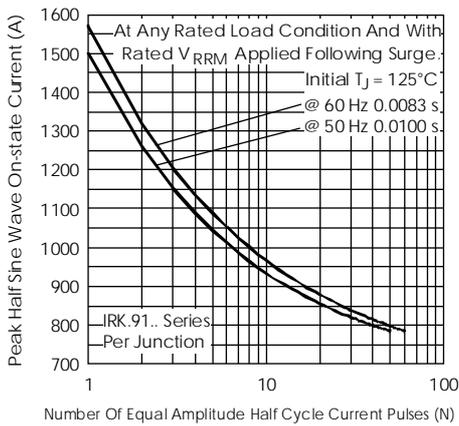


Fig. 50 - Maximum Non-Repetitive Surge Current

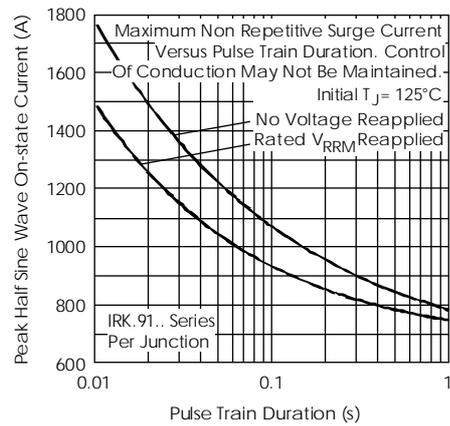


Fig. 51 - Maximum Non-Repetitive Surge Current

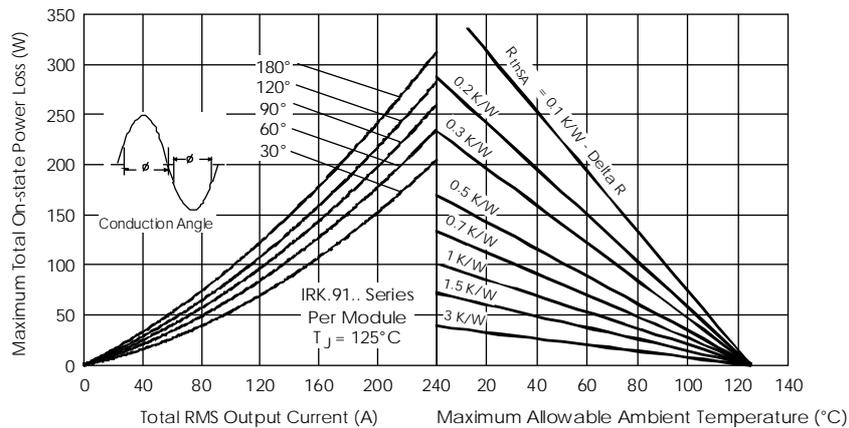


Fig. 52 - On-state Power Loss Characteristics

# POWER MODULES

IRK.71, .91 Series

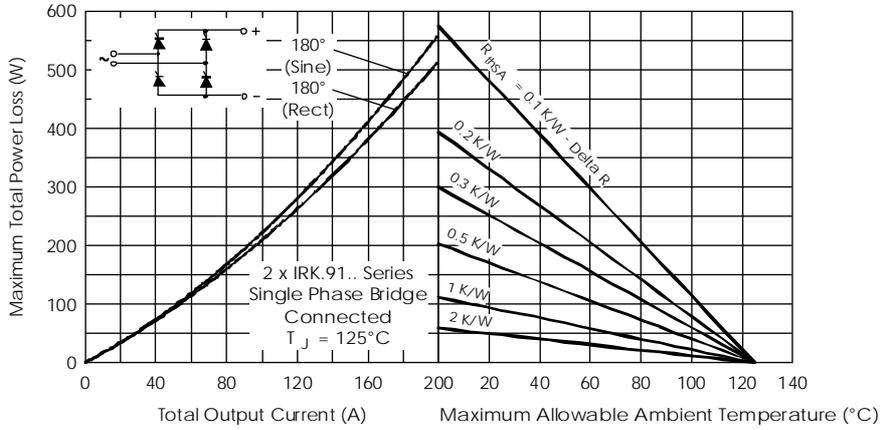


Fig. 53 - On-state Power Loss Characteristics

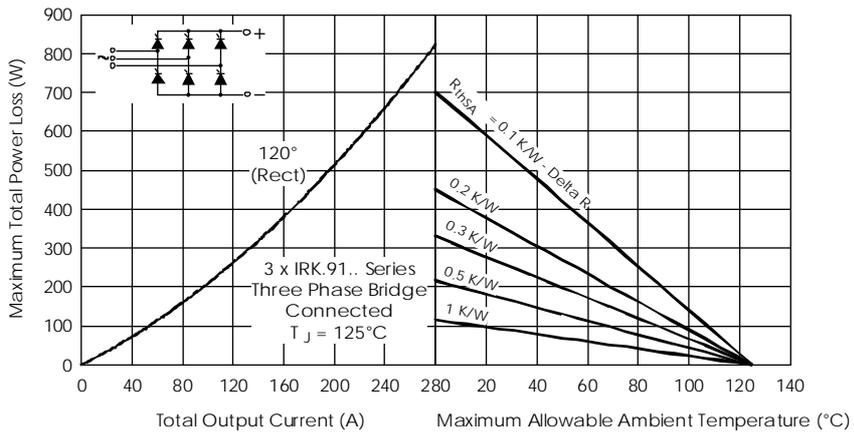


Fig. 54 - On-state Power Loss Characteristics

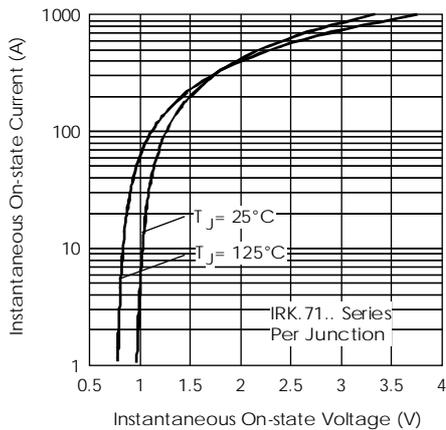


Fig. 55 - On-state Voltage Drop Characteristics

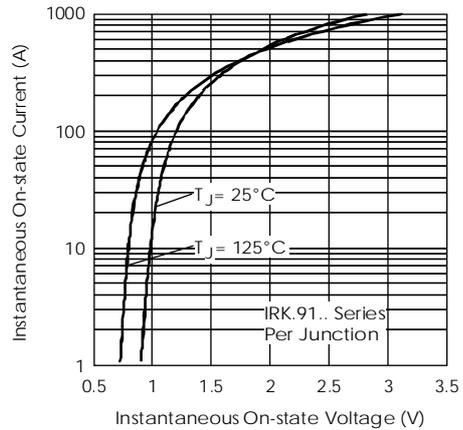


Fig. 56 - On-state Voltage Drop Characteristics

# POWER MODULES

## IRK.71, .91 Series

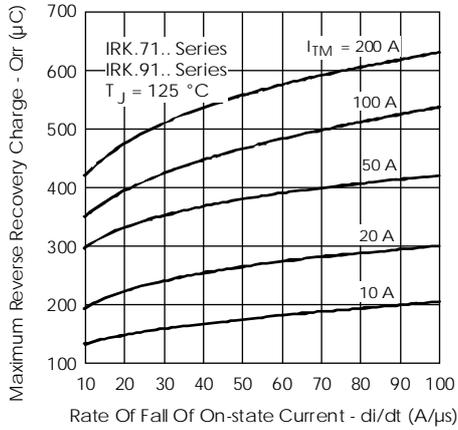


Fig. 57 - Recovery Charge Characteristics

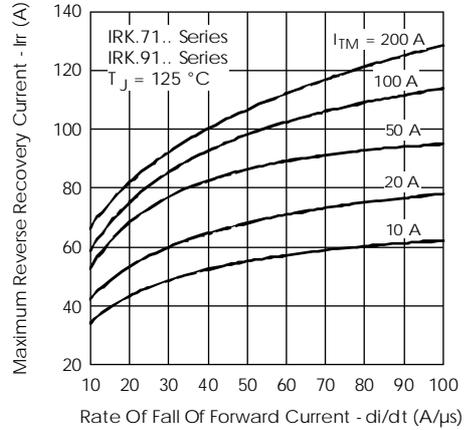


Fig. 58 - Recovery Current Characteristics

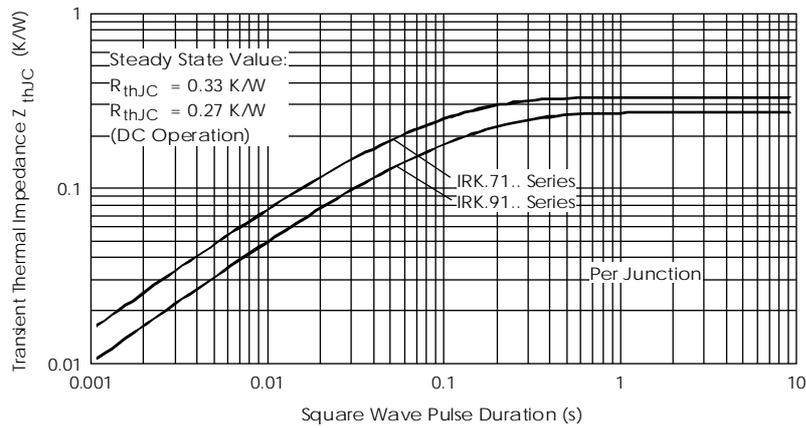


Fig. 59 - Thermal Impedance  $Z_{thJC}$  Characteristics

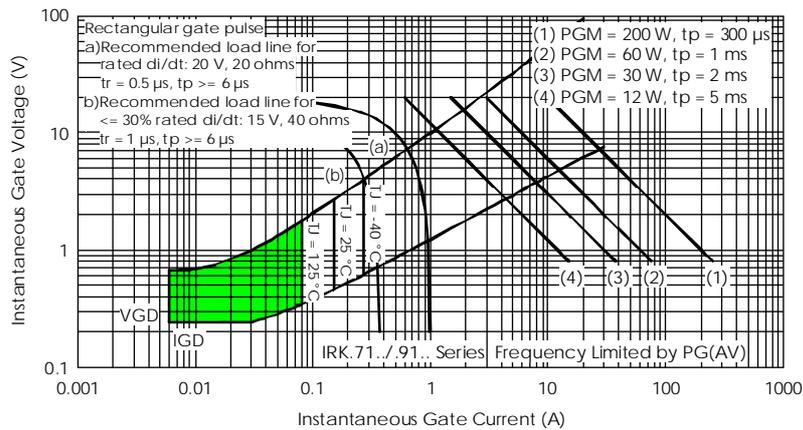


Fig. 60 - Gate Characteristics

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